

PUB4219 (PU4219), PUB4519 (PU4519)

Silicon PNP epitaxial planar type darlington

For power amplification

Complementary to PUB4119 (PU4119),

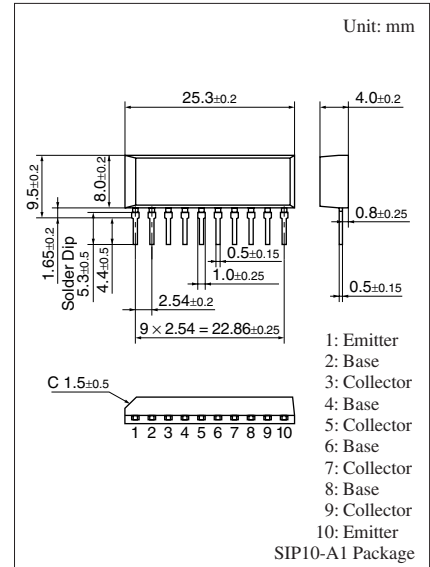
PUB4419 (PU4419)

■ Features

- High forward current transfer ratio h_{FE}
- High-speed switching
- PUB4219 (PU4219): PNP 4 elements
PUB4519 (PU4519): PNP 2 elements × 2

■ Absolute Maximum Ratings $T_C = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V_{CBO}	-60	V
Collector-emitter voltage (Base open)	V_{CEO}	-60	V
Emitter-base voltage (Collector open)	V_{EBO}	-5	V
Collector current	I_C	-2	A
Peak collector current	I_{CP}	-4	A
Collector power dissipation	P_C	15	W
		3.5	
	$T_a = 25^\circ\text{C}$		
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$



■ Electrical Characteristics $T_C = 25^\circ\text{C} \pm 3^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-emitter voltage (Base open)	V_{CEO}	$I_C = -30\text{ mA}, I_B = 0$	-60			V
Base-emitter voltage	V_{BE}	$V_{CE} = -4\text{ V}, I_C = -2\text{ A}$			-2.8	V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = -60\text{ V}, I_E = 0$			-1	mA
Collector-emitter cutoff current (Base open)	I_{CEO}	$V_{CE} = -30\text{ V}, I_B = 0$			-2	mA
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{EB} = -5\text{ V}, I_C = 0$			-2	mA
Forward current transfer ratio	h_{FE1}	$V_{CE} = -4\text{ V}, I_C = -1\text{ A}$	1 000			—
	h_{FE2}^*	$V_{CE} = -4\text{ V}, I_C = -2\text{ A}$	1 000		10 000	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -2\text{ A}, I_B = -8\text{ mA}$			-2.5	V
Transition frequency	f_T	$V_{CE} = -10\text{ V}, I_C = -0.5\text{ A}, f = 1\text{ MHz}$		20		MHz
Turn-on time	t_{on}	$I_C = -2\text{ A}$		0.4		μs
Storage time	t_{stg}	$I_{B1} = -8\text{ mA}, I_{B2} = 8\text{ mA}$		1.5		μs
Fall time	t_f	$V_{CC} = -50\text{ V}$		0.5		μs

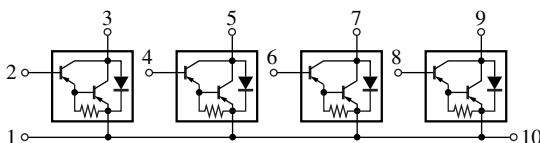
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *: Rank classification

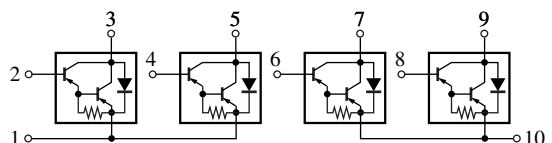
Rank	Free	P	Q
h_{FE}	1 000 to 10 000	2 000 to 10 000	1 000 to 5 000

■ Internal Connection

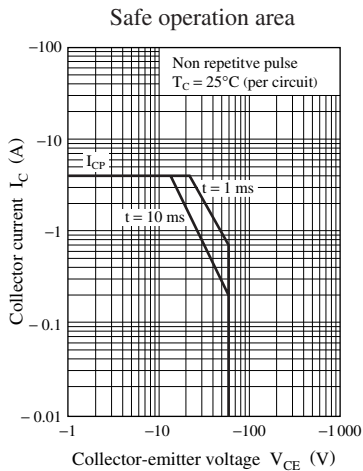
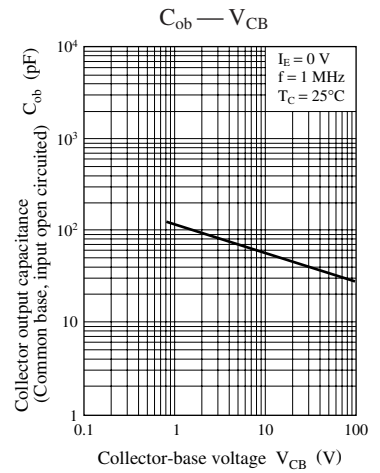
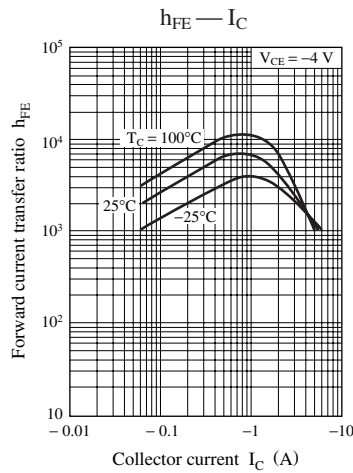
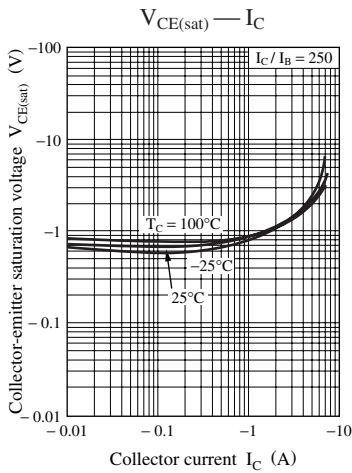
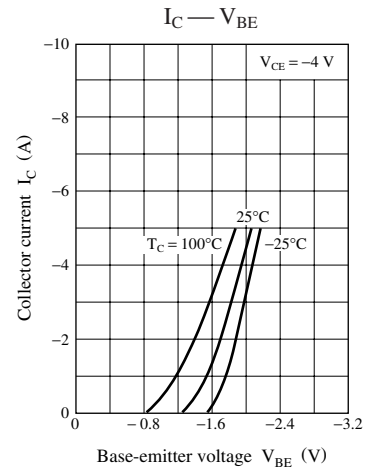
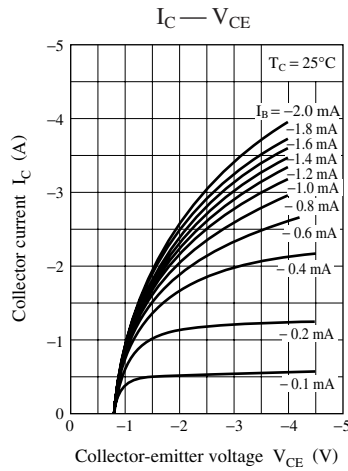
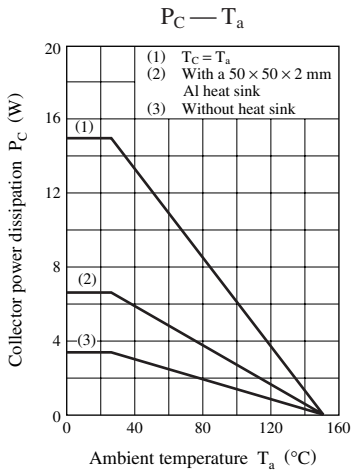
• PUB4219



• PUB4519



Note) The part numbers in the parenthesis show conventional part number.



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